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DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Oct 20 2003 Sep 19



HILIP

FEATURES

- High power gain
- Easy power control
- Gold metallization
- Good thermal stability
- Withstands full load mismatch.

APPLICATIONS

• Communications transmitters in the HF/VHF range with a nominal supply voltage of 12.5 V.

DESCRIPTION

Silicon N-channel enhancement mode vertical D-MOS transistor in an 8-lead SOT409A SMD package with a ceramic cap.



PIN	DESCRIPTION
1, 8	source
2, 3	gate
4, 5	source
6, 7	drain



QUICK REFERENCE DATA

RF performance at T_{mb} = 25 °C in a common source test circuit.

MODE OF OPERATION	f	V _{DS}	PL	G _p	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW, class-B	175	12.5	2	>10	>50

CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A, and SNW-FQ-302B.

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LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		-	40	V
V _{GS}	gate-source voltage		-	±20	V
I _D	drain current (DC)		-	1	A
P _{tot}	total power dissipation	$T_{mb} \le 85 \ ^{\circ}C$	-	5.7	W
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		-	200	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-mb}	thermal resistance from junction to mounting base	$T_{mb} \le 85 \text{ °C}; P_{tot} = 5.7 \text{ W}$	20.5	K/W



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CHARACTERISTICS

 T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)DSS}	drain-source breakdown voltage	$I_{D} = 3 \text{ mA}; V_{GS} = 0$	40	-	_	V
V _{GSth}	gate-source threshold voltage	$I_D = 3 \text{ mA}; V_{DS} = 10 \text{ V}$	2	-	4.5	V
I _{DSS}	drain-source leakage current	$V_{GS} = 0; V_{DS} = 12.5 V$	-	-	10	μA
I _{GSS}	gate-source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0$	-	-	1	μA
I _{DSX}	on-state drain current	$V_{GS} = 15 \text{ V}; V_{DS} = 10 \text{ V}$	-	1.3	-	А
R _{DSon}	drain-source on-state resistance	$I_D = 0.3 \text{ A}; V_{GS} = 15 \text{ V}$	-	3.5	4	Ω
9 _{fs}	forward transconductance	$I_D = 0.3 \text{ A}; V_{DS} = 10 \text{ V}$	80	135	-	mS
C _{is}	input capacitance	$V_{GS} = 0; V_{DS} = 12.5 V; f = 1 MHz$	-	5.3	-	pF
C _{os}	output capacitance	$V_{GS} = 0; V_{DS} = 12.5 V; f = 1 MHz$	-	7.8	-	pF
C _{rs}	feedback capacitance	$V_{GS} = 0; V_{DS} = 12.5 V; f = 1 MHz$	-	1.8	-	pF

V_{GS} group indicator

GROUP	LIMITS (V)		GROUP	LIMITS (V)		
	MIN.	MAX.		MIN.	MAX.	
A	2.0	2.1	0	3.3	3.4	
В	2.1	2.2	Р	3.4	3.5	
С	2.2	2.3	Q	3.5	3.6	
D	2.3	2.4	R	3.6	3.7	
E	2.4	2.5	S	3.7	3.8	
F	2.5	2.6	Т	3.8	3.9	
G	2.6	2.7	U	3.9	4.0	
Н	2.7	2.8	V	4.0	4.1	
J	2.8	2.9	W	4.1	4.2	
K	2.9	3.0	Х	4.2	4.3	
L	3.0	3.1	Y	4.3	4.4	
М	3.1	3.2	Z	4.4	4.5	
N	3.2	3.3				

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voltage as a function of drain current; typical values.











APPLICATION INFORMATION FOR CLASS-B OPERATION

 T_{mb} = 25 °C; R_{GS} = 237 $\Omega;$ unless otherwise specified.

RF performance in CW operation in a common source class-B test circuit.

MODE OF OPERATION	f (MHz)	V _{DS} (V)	I _{DQ} (mA)	P _L (W)	G _p (dB)	η _D (%)
CW, class-B	175	12.5	20	2	>10	>50
					typ. 13	typ. 55

Ruggedness in class-B operation

The BLF202 is capable of withstanding a load mismatch corresponding to VSWR = 50:1 through all phases under the following conditions: V_{DS} = 15.5 V; f = 175 MHz at rated load power.

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Fig.8 Power gain and efficiency as a functions of load power; typical values.



Class-B operation; V_{DS} = 12.5 V; I_{DQ} = 20 mA; f = 175 MHz.

Fig.9 Load power as a function of input power; typical values.



BLF202

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COMPONENT	DESCRIPTION	VALUE	DIMENSIONS	CATALOGUE NO.
C1, C11	film dielectric trimmer	2 to 9 pF		2222 809 09005
C2, C9	film dielectric trimmer	2 to 9 pF		2222 809 09002
C3, C5	multilayer ceramic chip capacitor; note 1	1 nF; 500 V		
C4, C6	multilayer ceramic chip capacitor	2 × 100 nF in parallel, 50 V		2222 852 47104
C7	Sprague electrolytic tantalum capacitor	2.2 μF; 35 V		
C8	multilayer ceramic chip capacitor; note 1	5.1 pF; 500 V		
C10	multilayer ceramic chip capacitor; note 1	9.1 pF; 500 V		
L1	8 turns enamelled 0.8 mm copper wire	137 nH	length 5.1 mm; int. dia. 4 mm; leads 2×5 mm	
L2, L3	stripline; note 2	81 Ω	8 mm × 2 mm	
L4	3 turns enamelled 1 mm copper wire	57 nH	length 5 mm; int. dia. 6 mm; leads 2×5 mm	
L5	9 turns enamelled 1 mm copper wire	355 nH	length 11 mm; int. dia. 7 mm; leads 2×5 mm	
L6	grade 3B Ferroxcube RF choke			4312 020 36642
R1	0.4 W metal film resistor	237 Ω		2322 151 72371
R2	0.4 W metal film resistor	1 kΩ		2322 151 71002
R3	0.4 W metal film resistor	1 MΩ		2322 151 71005
R4	10 turns cermet potentiometer	5 kΩ		
R5	0.4 W metal film resistor	7.5 kΩ		2322 151 77502
R6	1 W metal film resistor	10 Ω		2322 153 51009

List of components (see Fig.10)

Notes

1. American Technical Ceramics (ATC) capacitor, type 100B or other capacitor of the same quality.

2. The striplines are on a double copper-clad printed-circuit board, with PTFE fibre-glass dielectric (ϵ_r = 2.2), thickness 1.6 mm.

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Class B-operation; V_{DS} = 12.5 V; I_{DQ} = 20 mA; R_{GS} = 237 \ \Omega; P_L = 2 W.

Fig.12 Load impedance as a function of frequency (series components); typical values.



Fig.14 Power gain as a function of frequency; typical values.

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MOUNTING RECOMMENDATIONS

Both the metallized ground plate and the device leads contribute to the heat flow. It is recommended that the transistor be mounted on a grounded metallized area of the printed-circuit board. This area should be of maximum 0.8 mm thickness and include at least 12 x 0.5 diameter through metallized holes filled with solder.

A thermal resistance $R_{th(mb-h)}$ of 5 K/W can be achieved if heatsink compound is applied when the transistor is mounted on the printed-circuit board.



BLF202

BLF202 scattering parameters

$V_{DS} = 12.5$	V;	$I_D =$	20	mA;	note	1
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f /MU=)	s ₁₁		s ₂₁		s ₁₂		S ₂₂	
	s ₁₁	$\angle \Phi$	s ₂₁	$\angle \Phi$	s ₁₂	$\angle \Phi$	S ₂₂	$\angle \Phi$
5	1.00	-2.00	5.76	178.30	0.01	88.30	0.97	-2.40
10	1.00	-4.00	5.75	176.50	0.01	86.70	0.97	-4.90
20	1.00	-7.90	5.72	172.90	0.02	83.40	0.97	-9.70
30	0.99	-11.90	5.69	169.40	0.03	80.20	0.97	-14.50
40	0.99	-15.80	5.65	165.90	0.04	77.00	0.96	-19.30
50	0.98	-19.60	5.58	162.40	0.05	73.80	0.96	-23.90
60	0.97	-23.40	5.51	159.00	0.06	70.70	0.95	-28.50
70	0.96	-27.00	5.42	-155.70	0.07	67.70	0.94	-33.00
80	0.94	-30.70	5.33	152.40	0.08	64.80	0.93	-37.40
90	0.93	-34.10	5.23	149.30	0.09	62.00	0.92	-41.60
100	0.92	-37.50	5.12	146.40	0.10	59.40	0.92	-45.60
125	0.89	-45.60	4.86	139.30	0.12	53.10	0.89	-55.30
150	0.85	-53.00	4.58	132.60	0.13	47.20	0.87	-64.10
175	0.82	-59.80	4.29	126.60	0.14	42.00	0.85	-72.00
200	0.79	-66.00	4.03	121.20	0.15	37.70	0.83	-79.20
250	0.74	-77.00	3.55	111.30	0.17	29.30	0.79	-91.70
300	0.70	-86.30	3.15	103.30	0.17	23.10	0.77	-101.90
350	0.68	-94.30	2.80	96.00	0.18	17.30	0.76	-110.30
400	0.66	-101.40	2.52	89.80	0.18	12.90	0.75	-117.20
450	0.64	-107.80	2.27	83.80	0.18	8.60	0.74	-123.20
500	0.64	-113.50	2.07	78.80	0.18	5.20	0.74	-128.30
600	0.63	-123.80	1.75	69.60	0.17	-0.70	0.74	-136.60
700	0.64	-132.60	1.51	61.40	0.15	-5.30	0.75	-143.20
800	0.65	-140.60	1.32	54.40	0.14	-8.20	0.76	-148.60
900	0.67	-148.10	1.16	48.20	0.12	-9.70	0.77	-153.30
1000	0.68	-155.00	1.04	42.90	0.11	-9.20	0.78	-157.40

Note

1. For more extensive s-parameters see internet:

http://www.semiconductors.philips.com/markets/communications/wirelesscommunications/broadcast.

PACKAGE OUTLINE

Ceramic surface mounted package; 8 leads



SOT409A

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Printed in The Netherlands

613524/02/pp14

Date of release: 2003 Sep 19

Document order number: 9397 750 11595

SCA75

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